

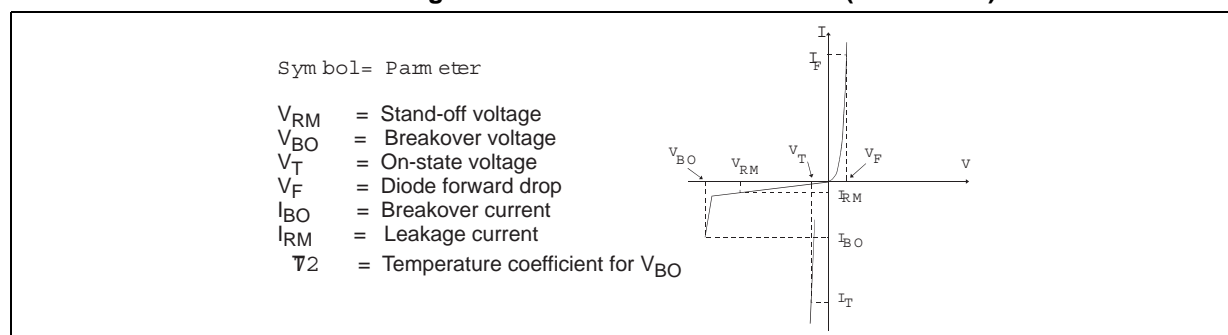
# 1 Characteristics

**Table 2. Absolute ratings (limiting values)**

Symbol	Parameter		Value	Unit
I <sub>TRM</sub>	Repetitive surge peak on state current for thyristor -30° C ≤ T <sub>amb</sub> ≤ 120° C	t <sub>p</sub> = 10 μs (Figure 3)	190	A
I <sub>FRM</sub>	Repetitive surge peak on state current for diode -30° C ≤ T <sub>amb</sub> ≤ 120° C			
di/dt	Critical rate of rise time on state current -30° C ≤ T <sub>amb</sub> ≤ 120° C		120	A/μs
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Maximum junction temperature		- 40 to + 150 + 125	° C
T <sub>oper</sub>	Operating temperature range		- 30 to + 120	° C
T <sub>L</sub>	Maximum lead temperature for soldering during 10s		260	° C

**Table 3. Thermal resistance**

Symbol	Parameter		Min.
$R_{th(j-a)}$	Thermal resistance junction to ambient	100	$^{\circ}\text{C/W}$

**Figure 2. Electrical characteristics (definitions)**

**Table 4. Electrical characteristics: diode (D) parameter**

Symbol	Test Conditions				Value	Unit
$V_F$	$I_F = 2\text{ A}$	$t_p \leq 500\text{ }\mu\text{s}$	$T_j = 25^{\circ}\text{C}$	MAX	1.7	V

**Table 5. Electrical characteristics: Thyristor (Th) and Zener (Z) parameters**

Symbol	Test Conditions		Min.	Typ.	Max	Unit
$I_{RM}$	$V_{RM} = 200\text{ V}$	$T_j = 25^{\circ}\text{C}$			1	$\mu\text{A}$
		$T_j = 125^{\circ}\text{C}$			10	$\mu\text{A}$
$V_{BO}$	at $I_{BO}$	$T_j = 25^{\circ}\text{C}$	206	220	233	V
$I_{BO}$	at $V_{BO}$	$T_j = 25^{\circ}\text{C}$			0.5	mA
$V_T$	$I_T = 2\text{ A}$	$t_p \leq 500\text{ }\mu\text{s}$			1.7	V
$\alpha_T$				0.27		V/ $^{\circ}\text{C}$

Figure 3. Test current waveform

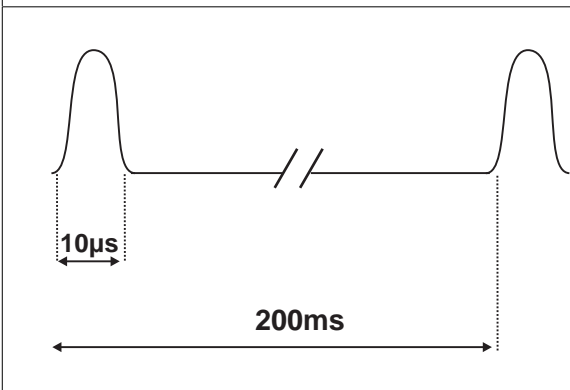


Figure 4. Relative variation of breakover current versus junction temperature

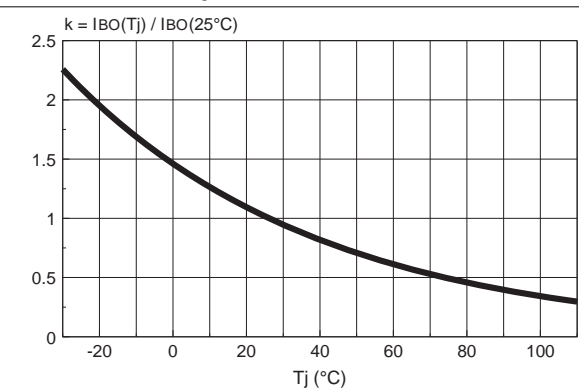
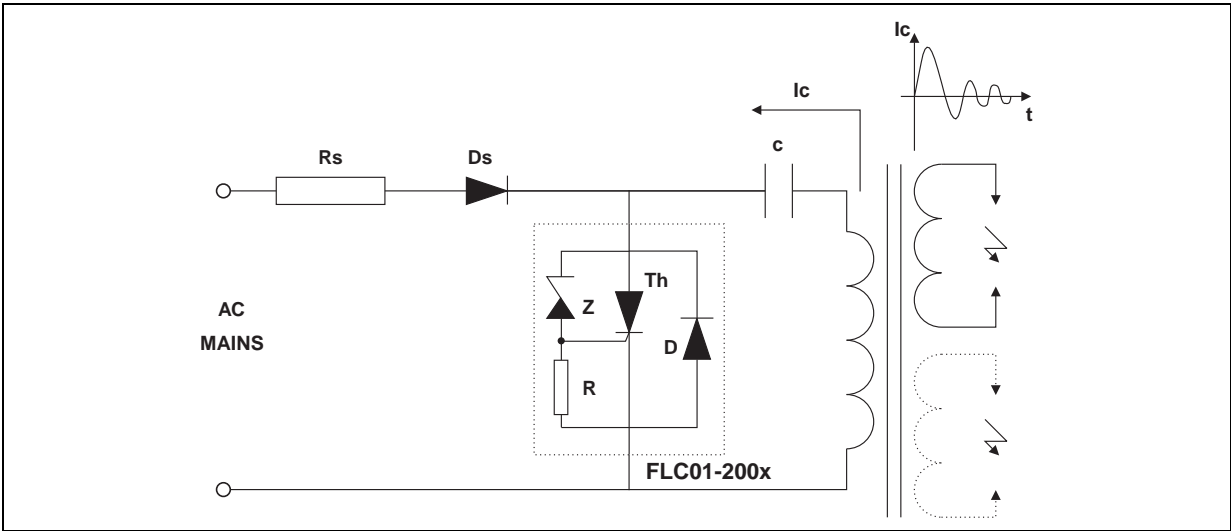


Figure 5. Basic application



The applications of the lighter using the capacitance discharge topology operate in 2 phases:

### Phase 1

The energy coming from the mains is stored into the capacitor C. For that, the AC voltage is rectified by the diode Ds.

### Phase 2

At the end of the phase 1, the voltage across the capacitor C reaches the avalanche threshold of the zener. Then a current flows through the gate of the thyristor Th which fires.

- The firing of the thyristor causes an alternating current to flow through the capacitor C
- The positive parts of this current flow through C, Th and the primary of the HV transformer
- The negative parts of the current flow through C, D and the primary of the HV transformer

### RS resistor calculation

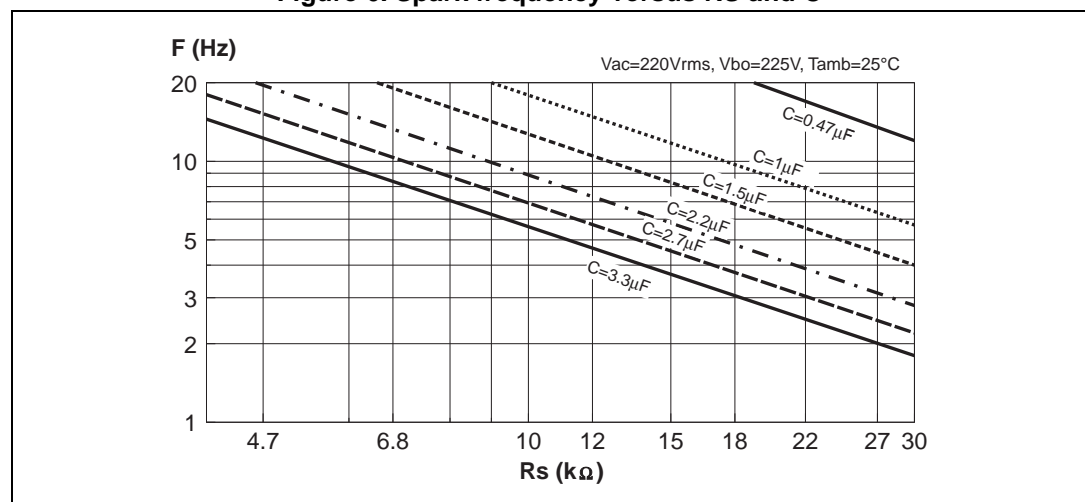
The Rs resistor allows, in addition with the capacitor C, the spark frequency to be adjusted and the current from the mains to be limited. Its value shall allow the thyristor Th to fire even in the worst case. In this case the system must fire with the lower RMS mains voltage value while the breakdown voltage and current of the FLC are at the maximum.

The maximum Rs value is equal to:

$$R_{smax} = \frac{(V_{AC \min} \cdot \sqrt{2}) - [V_{BO \max} \cdot (1 + \alpha T \cdot (T_{amb} - 25))]}{k \cdot I_{BO} (1)}$$

(1) See [Figure 4](#)

**Figure 6. Spark frequency versus RS and C**

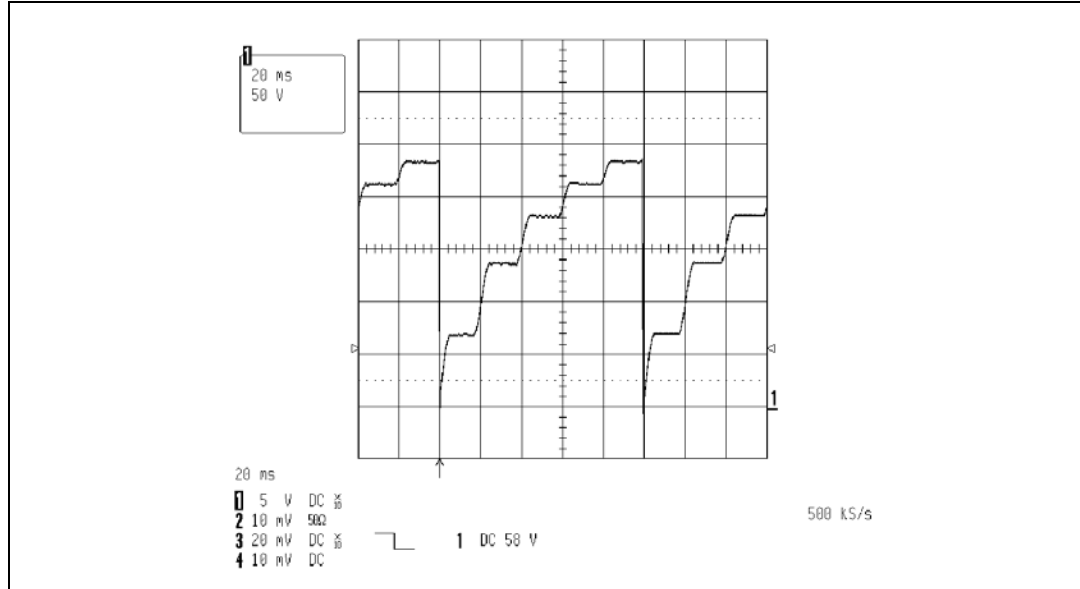


The couple Rs/C can be chosen with the previous curve.

Keep in mind the Rs maximum limit for which the system would not work when the AC mains is minimum.

The next curve on the next page shows the behavior with  $R_S = 15\text{ k}\Omega$  and  $C = 1\text{ }\mu\text{F}$ .

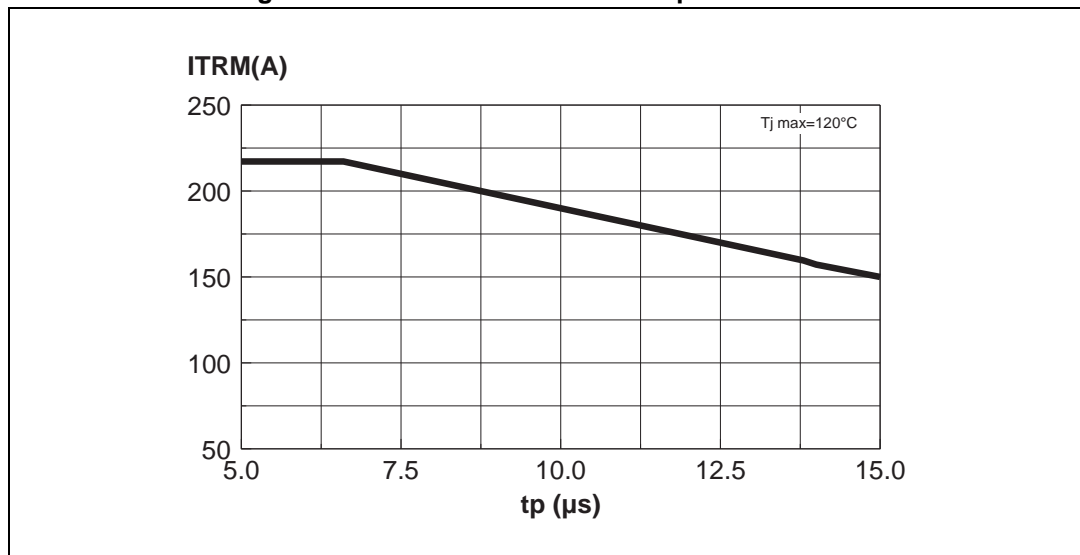
**Figure 7. Voltage across the capacitance with  $R_S = 15\text{ k}\Omega$ ,  $C = 1\text{ }\mu\text{F}$  and  $V_{BO} = 225\text{ V}$**



### Peak current limit

This component is designed to withstand  $I_{TRM} = 190\text{ A}$  for a pulse duration of  $10\text{ }\mu\text{s}$  for an ambient temperature of  $120^\circ\text{C}$  in repetitive surge. The curve of peak current versus the pulse duration allows us to verify if the application is within the FLC operating limit.

**Figure 8. Peak current limit versus pulse duration**



### Power losses (for $10\text{ }\mu\text{s}$ , see [Figure 3](#))

To evaluate the power losses, please use the following equations:

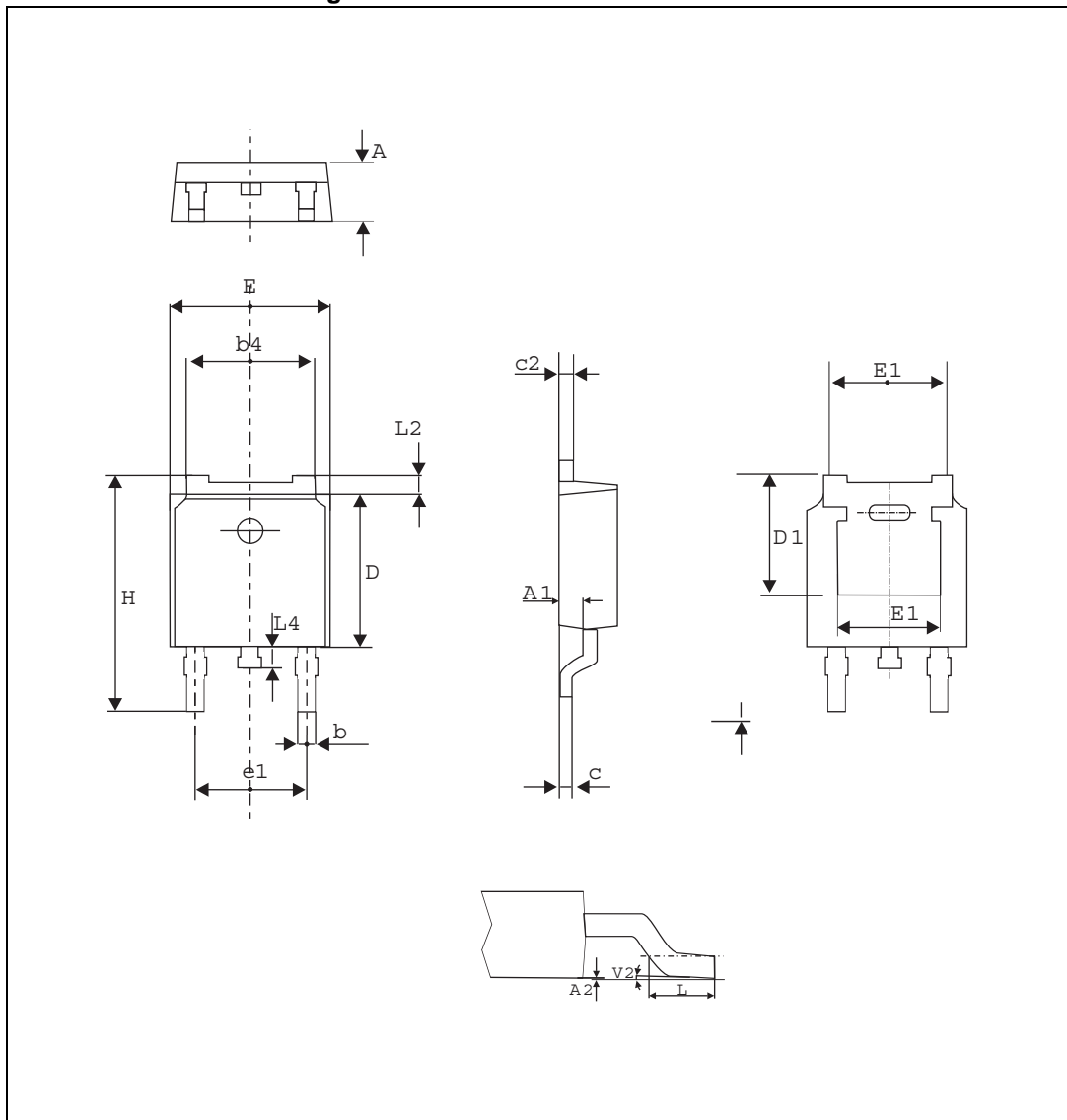
- For the thyristor:  $P = 1.18 \times I_{T(AV)} + 0.035 I_{T(RMS)}^2$
- For the diode:  $P = 0.67 \times I_{F(AV)} + 0.106 I_{F(RMS)}^2$

## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Recommended torque: 0.4 to 0.6 N·m

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**Figure 9. DPAK dimension definitions**



**Note:** *this package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.*

### Table 6. DPAK dimension values

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.18		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
b	0.64		0.90	0.025		0.035
b4	4.95		5.46	0.195		0.215
c	0.46		0.61	0.018		0.024
c2	0.46		0.60	0.018		0.023
D	5.97		6.22	0.235		0.244
D1	5.10			0.201		
E	6.35		6.73	0.250		0.264
E1		4.32			0.170	
e1	4.40		4.70	0.173		0.185
H	9.35		10.40	0.368		0.409
L	1.00		1.78	0.039		0.070
L2			1.27			0.05
L4	0.60		1.02	0.023		0.040
V2	0°		8°	0°		8°

**Figure 10. Footprint (dimensions in mm)**

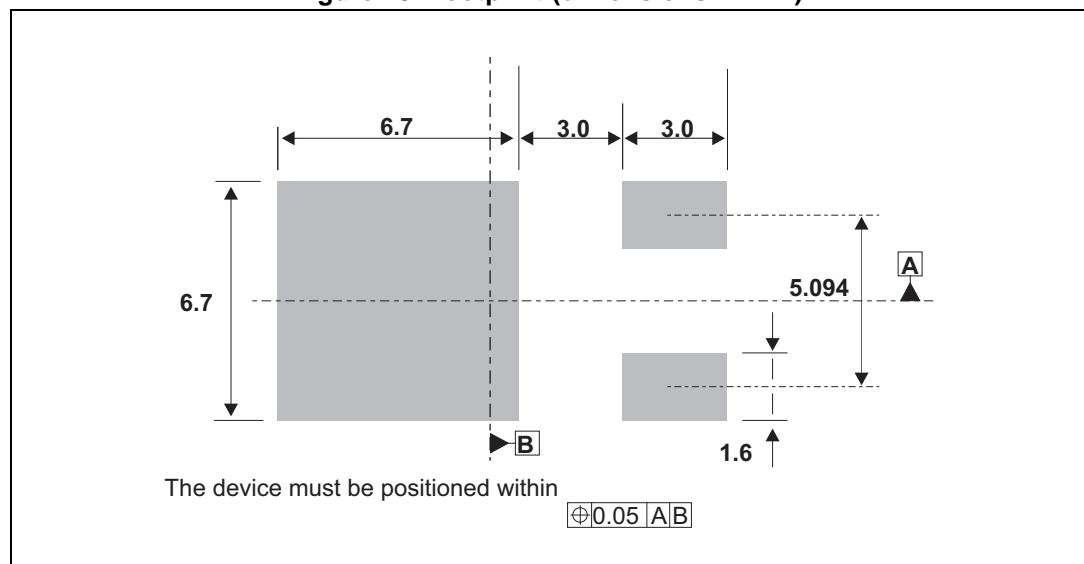
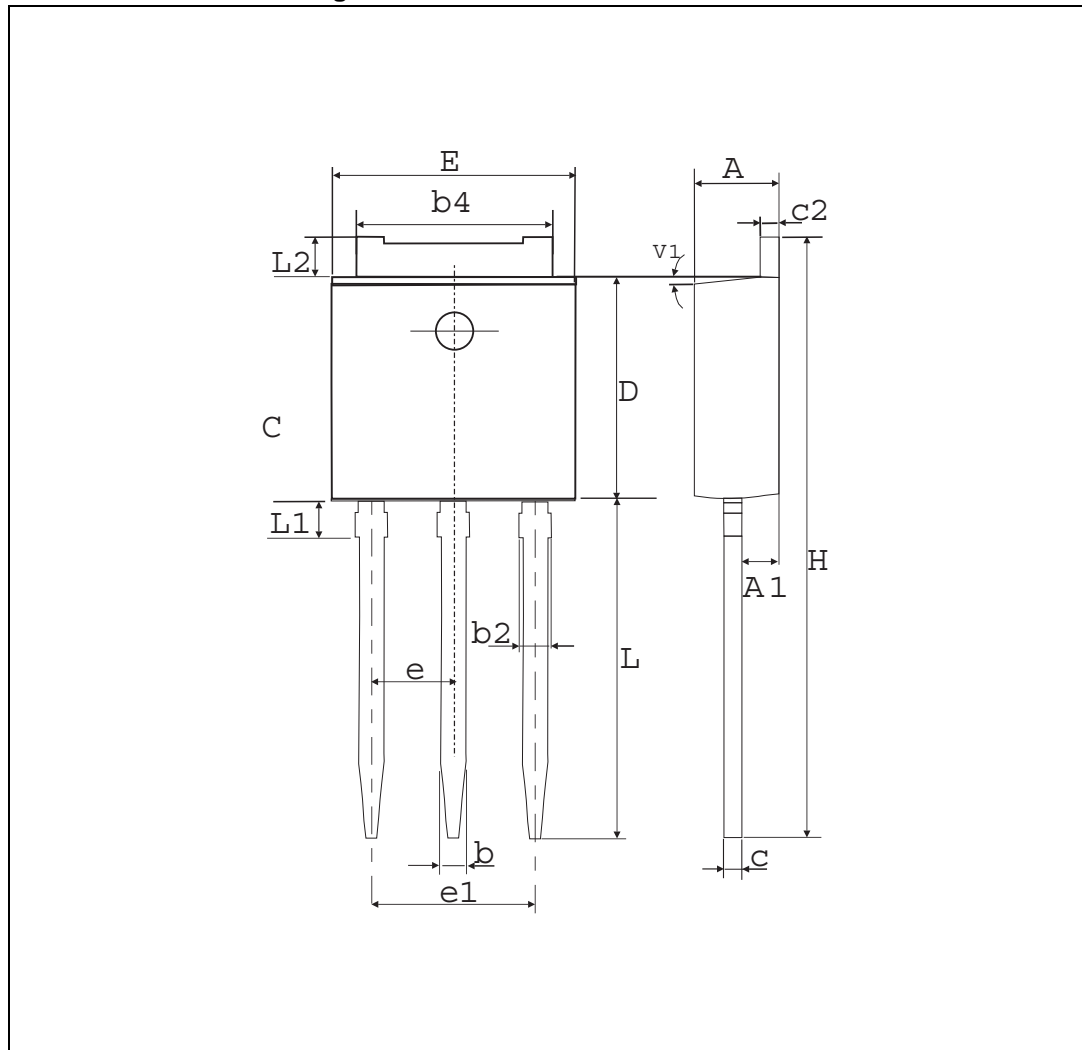


Figure 11. IPAK dimension definitions



**Note:** *this package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.*

Table 7. IPAK dimension values

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
b	0.64		0.90	0.025		0.035
b2			0.95			0.037
b4	5.20		5.43	0.204		0.213
c	0.45		0.60	0.017		0.023
c2	0.46		0.60	0.018		0.023
D	6		6.20	0.236		0.244
E	6.40		6.70	0.252		0.263
e		2.28			0.090	
e1	4.40		4.60	0.173		0.181
H		16.10			0.634	
L	9		9.60	0.354		0.377
L1	0.8		1.20	0.031		0.047
L2		0.80	1.25		0.031	0.049
V1		10°			10°	



### 3 Ordering information

Figure 12. Order information scheme

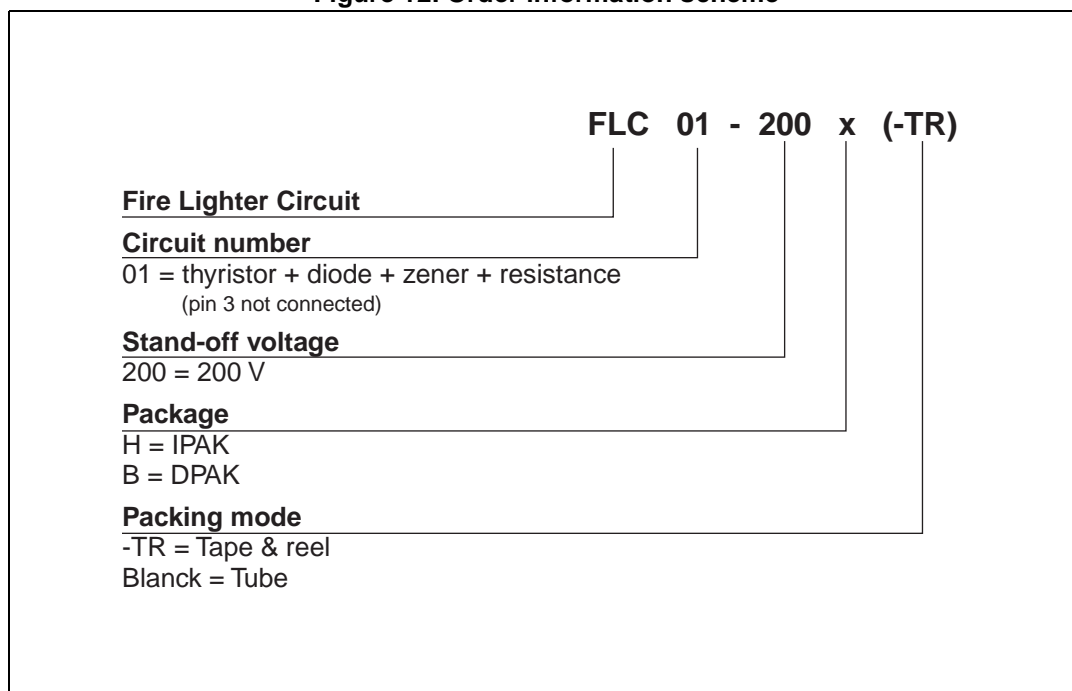


Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
FLC01-200H	FLC01-200H	IPAK	0.4 g	75	Tube
FLC01-200B	FLC01-200B	DPAK	0.3 g	75	Tube
FLC01-200B-TR	FLC01-200B	DPAK	0.3 g	2500	Tape and reel

### 4 Revision history

Table 9. Document revision history

Date	Revision	Changes
April-2002	6C	First issue.
27-May-2014	7	Updated DPAK and IPAK package information and reformatted to current standard.

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